LMC7101Q-Q1 Automotive, Tiny, Low-Power Operational Amplifier With Rail-to-Rail Input and Output

1 Features

- AEC-Q100 qualified for automotive applications:
  - Temperature: –40°C to +125°C, T_A
- Tiny 5-Pin SOT-23 package saves space; typical circuit layouts take half the space of 8-pin SOIC designs
- Specified for 2.7V, 3V, 5V, 15V supplies
- Typical supply current 0.5mA at 5V
- Typical total harmonic distortion of 0.01% at 5V
- 1MHz gain bandwidth
- Similar to popular LMC6482 and LMC6484
- Rail-to-rail input and output

2 Applications

- Mobile communications
- Notebooks and PDAs
- Battery-powered products
- Sensor interface
- Automotive applications

3 Description

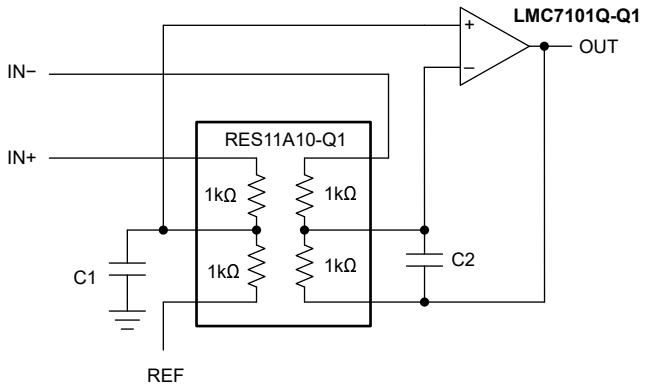
The LMC7101Q-Q1 device is a high-performance, automotive, CMOS operational amplifier available in a space-saving, 5-pin, SOT-23 tiny package. This design makes the LMC7101Q-Q1 an excellent choice for space- and weight-critical designs. The performance is similar to the single amplifier of the LMC6482 and LMC6484, with rail-to-rail input and output, high open-loop gain, low distortion, and low-supply currents.

The main benefits of the tiny package are most apparent in space-constrained applications. The tiny amplifiers can be placed on a board where needed, thus simplifying board layout.

Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
LMC7101Q-Q1	DBV (SOT-23, 5)	2.9mm × 2.8mm

(1) For more information, see Section 10.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Difference Amplifier Application With RES11A-Q1

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4 Pin Configuration and Functions

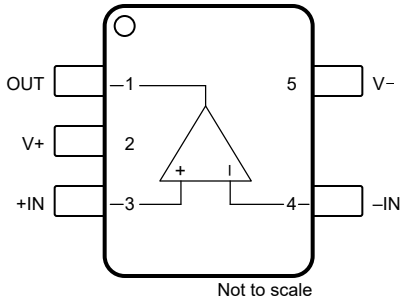


Figure 4-1. DBV Package, 5-Pin SOT-23 (Top View)

Table 4-1. Pin Functions

PIN		TYPE	DESCRIPTION
NO.	NAME		
1	OUT	Output	Output
2	V+	Power	Positive supply
3	+IN	Input	Noninverting input
4	−IN	Input	Inverting input
5	V−	Power	Negative supply

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	MAX	UNIT
	Difference Input voltage		±Supply voltage	V
	Voltage at input and output pins	(V–) – 0.3	(V+) + 0.3	V
V_S	Supply voltage, V_S = (V+) – (V–)		16	V
	Current at input pin	–5	5	mA
	Current at output pin(3)	–35	35	mA
	Current at power supply pin		35	mA
	Lead temperature (soldering, 10s)		260	°C
T_J	Junction temperature(4)		150	°C
T_{stg}	Storage temperature	–65	150	°C

(1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) If Military/Aerospace specified devices are required, contact the TI Sales Office or Distributors for availability and specifications.
(3) Applies to both single-supply and split-supply operation. Continuous short operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature at 150°C
(4) The maximum power dissipation is a function of $T_{J(MAX)}$, $R_{\theta JA}$ and T_A. The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(MAX)} – T_A) / R_{\theta JA}$. All numbers apply for packages soldered directly into a PC board.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101	±1000	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_S	Supply voltage, V_S = (V+) – (V–)	2.7		15.5	V
T_A	Ambient temperature	–40		125	°C

5.4 Thermal Information

THERMAL METRIC(1)		LMC7101Q-Q1 DBV (SOT-23) 5 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	193.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case(top) thermal resistance	128.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	88.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	66.8	°C/W
ψ_{JB}	Junction-to-board characterization parameter	88.6	°C/W
$R_{\theta JC(bot)}$	Junction-to-case(bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

5.5 Electrical Characteristics for V_S = 2.7V or ±1.35V

at T_A = 25°C, V+ = 2.7V, V– = 0V, V_{CM} = V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±9	mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	V+ = 1.35V to 1.65V, V– = –1.35V to –1.65V, V_{CM} = 0V		45	60		dB
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
INPUT VOLTAGE							
V_{CM}	Common-mode voltage	For CMRR ≥ 47dB	Positive	2.7	3		V
			Negative		0	0	
CMRR	Common-mode rejection	0V ≤ V_{CM} ≤ 2.7V		47	70		dB
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Common-mode input capacitance				3		pF
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				0.6		MHz
SR	Slew rate(1)	V+ = 15V, 10V step, G = 1, R_L = 100kΩ to 7.5V, V_{OUT} = $10V_{PP}$, f = 1kHz			0.7		V/µs
OUTPUT							
V_O	Voltage output swing	Positive rail	R_L = 2kΩ	2.15	2.45		V
			R_L = 10kΩ	2.64	2.68		
		Negative rail	R_L = 2kΩ		0.25	0.5	
			R_L = 10kΩ		0.025	0.06	
POWER SUPPLY							
I_Q	Quiescent current per amplifier				500	810	µA
		T_A = –40°C to +125°C			500	950	

(1) Number specified is the slower of the positive and negative slew rates.

5.6 Electrical Characteristics for V_S = 3V or ±1.5V

at T_A = 25°C, V+ = 3V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±7	mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	V+ = 1.5V to 7.5V, V– = –1.5V to –7.5V, V_{OUT} = V_{CM} = 0V		60	80		dB
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	For CMRR ≥ 47dB	Positive	3	3.3		V
			Negative		0	0	
CMRR	Common-mode rejection	0V ≤ V_{CM} ≤ 3V		47	70		dB
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Common-mode input capacitance				3		pF
OUTPUT							
V_O	Voltage output swing	Positive rail	R_L = 2kΩ	2.6	2.8		V
			R_L = 600Ω	2.5	2.7		
		Negative rail	R_L = 2kΩ		0.2	0.4	
			R_L = 600Ω		0.37	0.6	
POWER SUPPLY							
I_Q	Quiescent current per amplifier				500	810	µA
		T_A = –40°C to +125°C			500	950	

5.7 Electrical Characteristics for V_S = 5V or ±2.5V

at T_A = 25°C, V+ = 5V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.11	±7	mV
		T_A = –40°C to +125°C			±0.11	±9	
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power supply rejection ratio	Positive V+ = 5V to 15V V– = 0V, V_{OUT} = 1.5V		65	82		dB
			T_A = –40°C to +125°C	62	82		
		Negative V+ = –5V to –15V V– = 0V, V_{OUT} = –1.5V		65	82		
			T_A = –40°C to +125°C	62	82		
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
NOISE							
THD	Total harmonic distortion	f = 10kHz, G = – 2V/V, R_L = 10kΩ, V_{OUT} = $4V_{pp}$			0.01		%
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	To positive rail CMRR > 50dB		5.2	5.3		V
			T_A = –40°C to +125°C	4.8	5.3		
		To negative rail CMRR > 50dB			–0.3	–0.2	
			T_A = –40°C to +125°C		–0.3	0.2	
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤ 5V		52	75		dB
		0.2V ≤ V_{CM} ≤ 4.8V, T_A = –40°C to +125°C		51	74		
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Input capacitance				3		pF
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				1		MHz
SR	Slew rate				1		V/µs
OUTPUT							
V_O	Voltage output swing	Positive rail R_L = 2kΩ		4.7	4.9		V
			T_A = –40°C to +125°C	4.54	4.9		
		Negative rail R_L = 2kΩ			0.1	0.18	
			T_A = –40°C to +125°C		0.1	0.28	
		Positive rail R_L = 600Ω		4.5	4.7		
			T_A = –40°C to +125°C	4.28	4.7		
		Negative rail R_L = 600Ω			0.3	0.5	
			T_A = –40°C to +125°C		0.3	0.8	
I_{SC}	Short-circuit current	Sourcing V_{OUT} = 0V		16	24		mA
			T_A = –40°C to +125°C	9	24		
		Sinking V_{OUT} = 5V		11	19		
			T_A = –40°C to +125°C	5.8	19		
POWER SUPPLY							
I_Q	Quiescent current per amplifier				0.5	0.85	mA
		T_A = –40°C to +125°C			0.5	1	

5.8 Electrical Characteristics for V_S = 15V or ±7.5V

at T_A = 25°C, V+ = 15V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V_{OS}	Input offset voltage				±0.26		mV
dV_{OS}/dT	Input offset voltage drift	T_A = –40°C to +125°C			1		µV/°C
PSRR	Power-supply rejection ratio	Positive V+ = 5V to 15V, V– = 0V, V_{OUT} = 1.5V		62	82		dB
			T_A = –40°C to +125°C	60	82		
		Negative V+ = –5V to –15V, V– = 0V, V_{OUT} = –1.5V		65	82		
			T_A = –40°C to +125°C	62	82		
INPUT BIAS CURRENT							
I_B	Input bias current				±1		pA
		T_A = –40°C to +125°C				±1000	
I_{OS}	Input offset current				±0.5		pA
		T_A = –40°C to +125°C				±2000	
NOISE							
e_n	Input voltage noise density	f = 1kHz, V_{CM} = 1V			37		nV/√Hz
i_n	Input current noise density	f = 1kHz			6.8		fA/√Hz
THD	Total harmonic distortion	f = 1kHz, G = – 2V/V, R_L = 10kΩ, V_{OUT} = 8.5V_{pp}			0.01		%
INPUT VOLTAGE							
V_{CM}	Input common-mode voltage	To positive rail V+ = 15V, CMRR > 50dB		15.2	15.3		V
			T_A = –40°C to +125°C	14.8	15.3		
		To negative rail V+ = 15V, CMRR > 50dB			–0.3	–0.2	
			T_A = –40°C to +125°C		–0.3	0.2	
CMRR	Common-mode rejection ratio	0V ≤ V_{CM} ≤15V		62	82		dB
		0.2V ≤ V_{CM} ≤ 14.8V, T_A = –40°C to +125°C		60	82		
INPUT IMPEDANCE							
R_{IN}	Input resistance				> 1		TΩ
C_{IN}	Input capacitance				3		pF
OPEN-LOOP GAIN							
A_{OL}	Open-loop voltage gain	Sourcing 7.5V < V_O < 12.5V, V_{CM} = 1.5V R_L = 2kΩ to 7.5V		80	340		V/mV
			T_A = –40°C to +125°C	30	340		
		Sinking 2.5V < V_O < 7.5V, V_{CM} = 1.5V R_L = 2kΩ to 7.5V		15	24		
			T_A = –40°C to +125°C	4	24		
		Sourcing, V_{CM} = 1.5V, 7.5V < V_O < 12.5V, R_L = 600Ω		34	300		
		Sinking, V_{CM} = 1.5V, 2.5V < V_O < 7.5V, R_L = 600Ω		6	15		

5.8 Electrical Characteristics for V_S = 15V or ±7.5V (continued)

at T_A = 25°C, V+ = 15V, V– = 0V, V_{CM} = 1.5V, V_{OUT} = V+ / 2, and R_L = 1MΩ connected to V+ / 2 (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
FREQUENCY RESPONSE							
GBW	Gain bandwidth product				1.1		MHz
SR	Slew rate(1)	10V step, R_L = 100kΩ to 7.5V V_{OUT} = 10V_{PP}, f = 1kHz		0.5	1.1		V/µs
			T_A = –40°C to +125°C	0.4	1.1		
θ_m	Phase margin				45		°
G_m	Gain margin				10		dB
OUTPUT							
V_O	Voltage output swing	Positive rail R_L = 2kΩ		14.4	14.7		V
			T_A = –40°C to +125°C	14.2	14.7		
		Negative rail R_L = 2kΩ			0.16	0.32	
			T_A = –40°C to +125°C		0.16	0.45	
		Positive rail R_L = 600Ω		13.4	14.1		
			T_A = –40°C to +125°C	12.85	14.1		
		Negative rail R_L = 600Ω			0.5	1	
			T_A = –40°C to +125°C		0.5	1.5	
I_{SC}	Short-circuit current(2)	Sourcing V_{OUT} = 0V		30	50		mA
			T_A = –40°C to +125°C	20	50		
		Sinking V_{OUT} = 12V		30	50		
			T_A = –40°C to +125°C	20	50		
POWER SUPPLY							
I_Q	Quiescent current per amplifier				0.8	1.5	mA
		T_A = –40°C to +125°C			0.8	1.75	

(1) Number specified is the slower of the positive and negative slew rates.
(2) Do not short circuit output to V+ when V+ is greater than 12V or reliability can be adversely affected.

5.9 Typical Characteristics for V_S = 2.7V

at V+ = 2.7V, V– = 0V, and T_A = 25°C (unless otherwise specified)

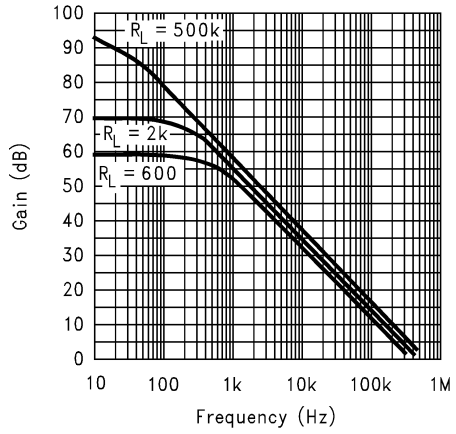


Figure 5-1. Open-Loop Frequency Response

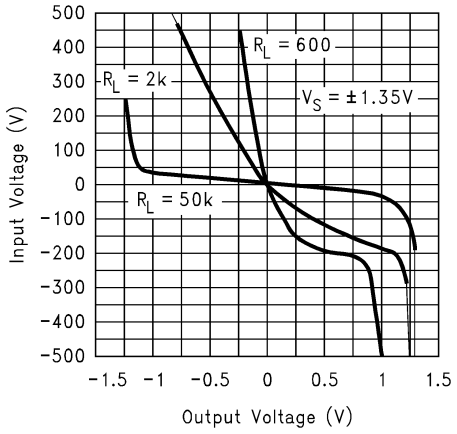


Figure 5-2. Input Voltage vs Output Voltage

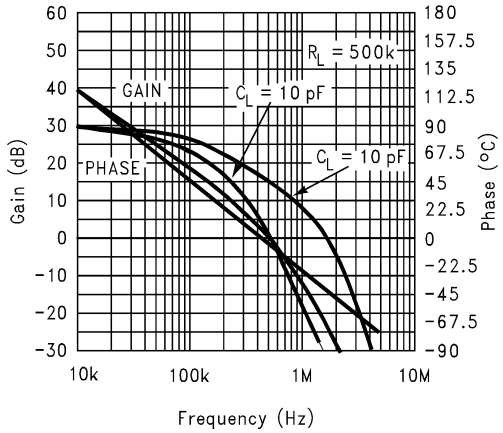


Figure 5-3. Gain and Phase vs Capacitance Load

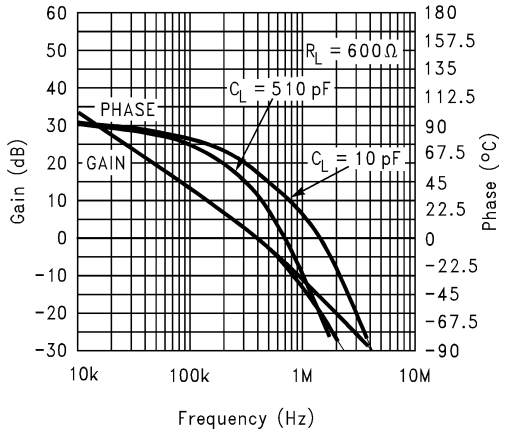


Figure 5-4. Gain and Phase vs Capacitance Load

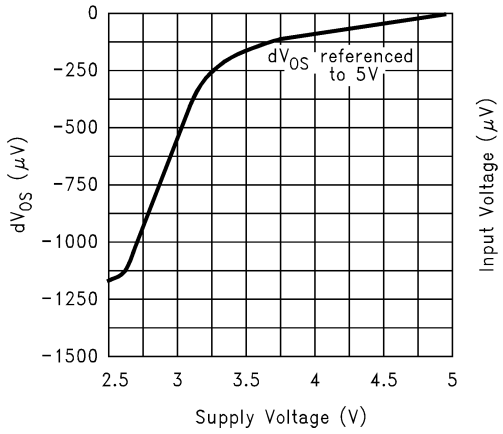
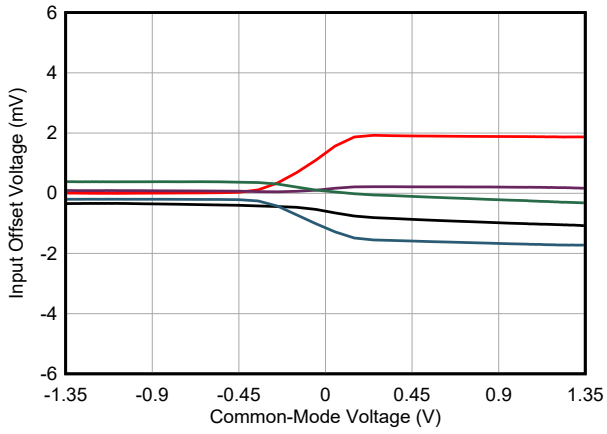


Figure 5-5. dV_{OS} vs Supply Voltage



5 typical units

Figure 5-6. Input Offset Voltage vs Common-Mode Voltage

5.9 Typical Characteristics for V_S = 2.7V (continued)

at V+ = 2.7V, V– = 0V, and T_A = 25°C (unless otherwise specified)

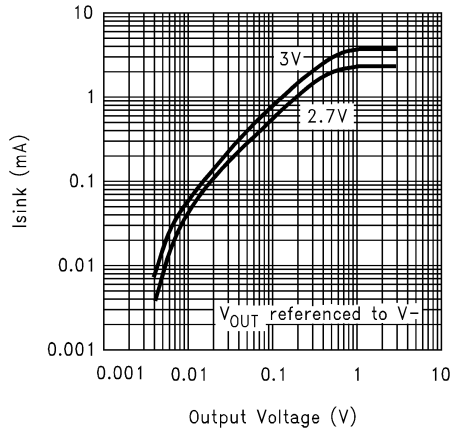


Figure 5-7. Sinking Current vs Output Voltage

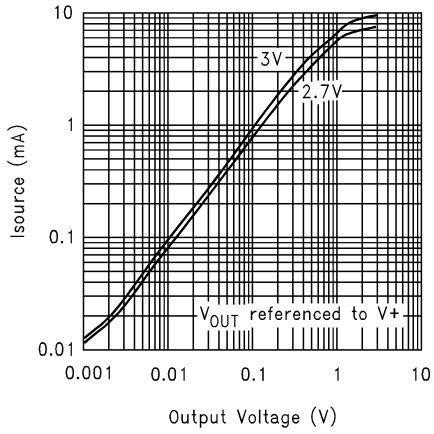


Figure 5-8. Sourcing Current vs Output Voltage

5.10 Typical Characteristics for V_S = 3V

at V+ = 3V, V– = 0V, and T_A = 25°C (unless otherwise specified)

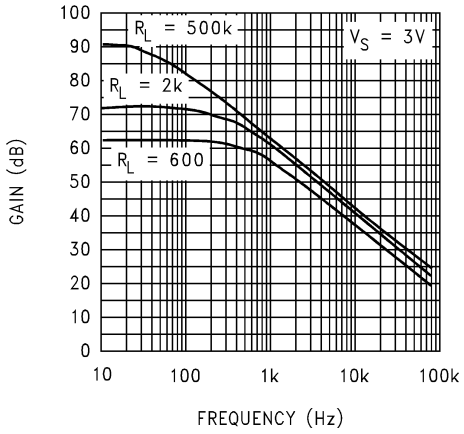


Figure 5-9. Open-Loop Frequency Response

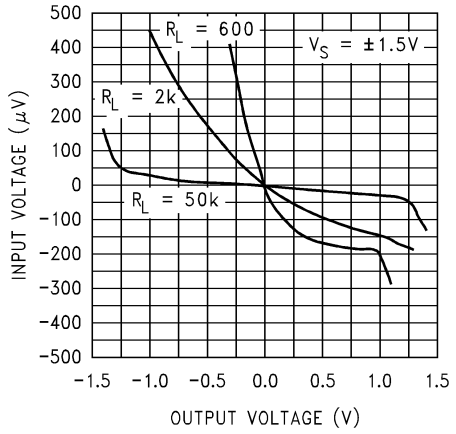


Figure 5-10. Input Voltage vs Output Voltage

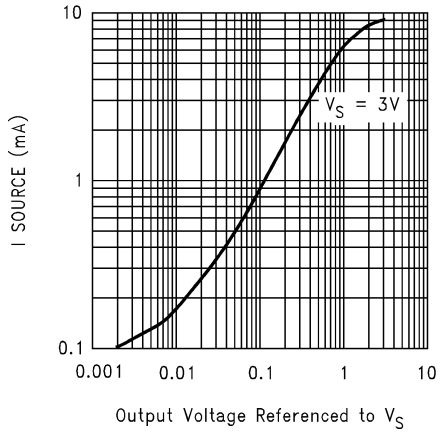


Figure 5-11. Sourcing Current vs Output Voltage

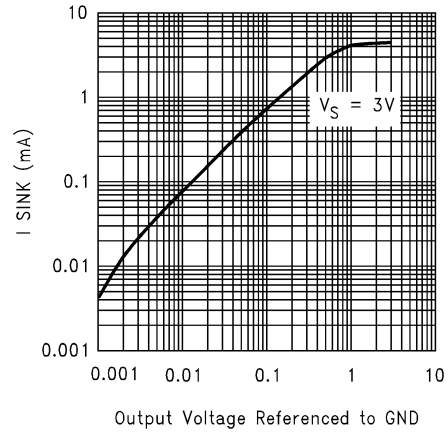


Figure 5-12. Sinking Current vs Output Voltage

5.11 Typical Characteristics for V_S = 5V

at V+ = 5V, V– = 0V, and T_A = 25°C (unless otherwise specified)

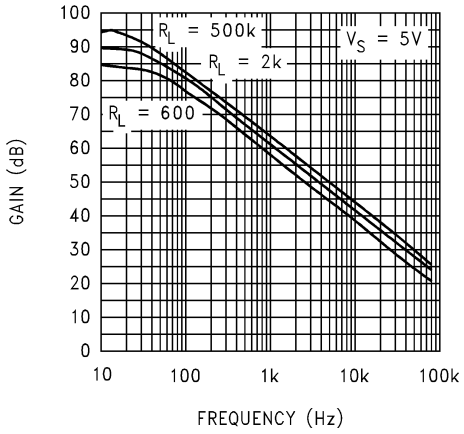


Figure 5-13. Open-Loop Frequency Response

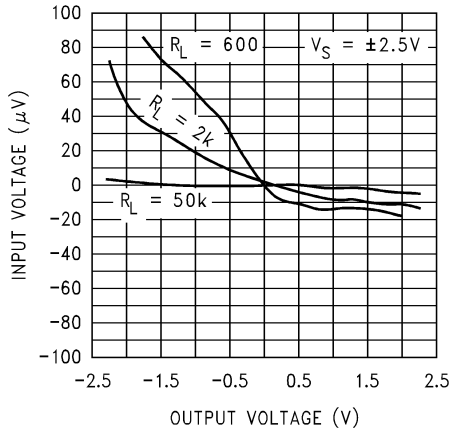


Figure 5-14. Input Voltage vs Output Voltage

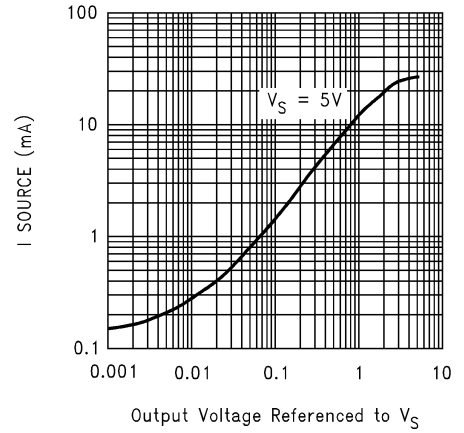


Figure 5-15. Sourcing Current vs Output Voltage

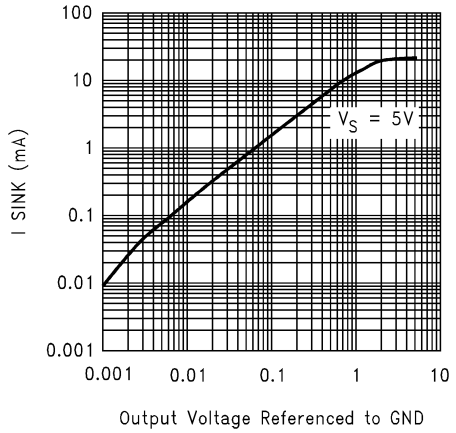


Figure 5-16. Sinking Current vs Output Voltage

5.12 Typical Characteristics for V_S = 15V

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

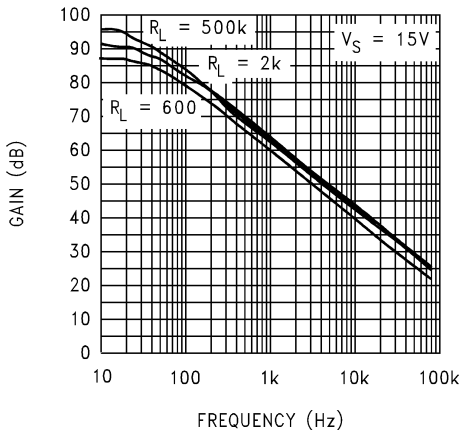


Figure 5-17. Open-Loop Frequency Response

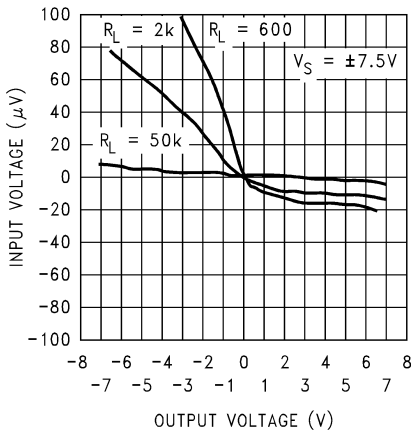


Figure 5-18. Input Voltage vs Output Voltage

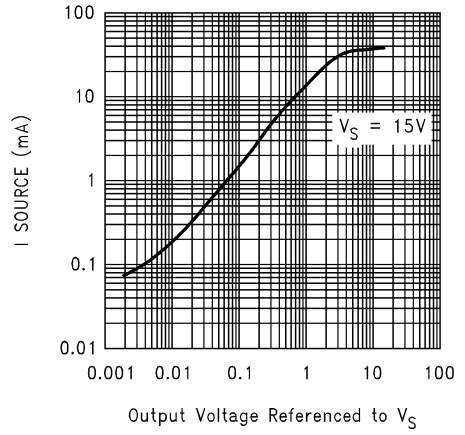


Figure 5-19. Sourcing Current vs Output Voltage

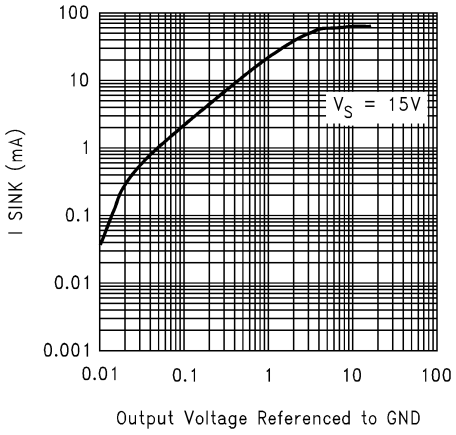


Figure 5-20. Sinking Current vs Output Voltage

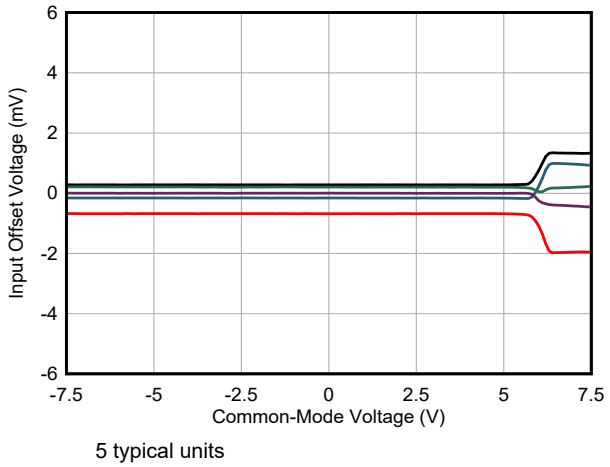


Figure 5-21. Input Offset Voltage vs Common-Mode Voltage

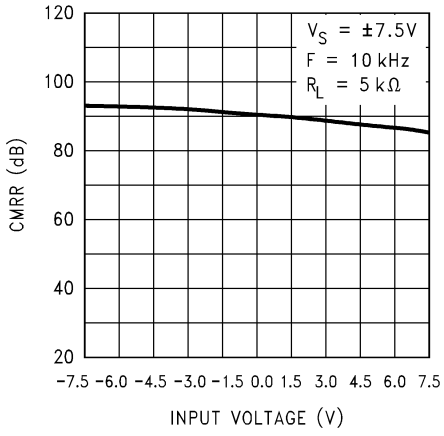


Figure 5-22. CMRR vs Input Voltage

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

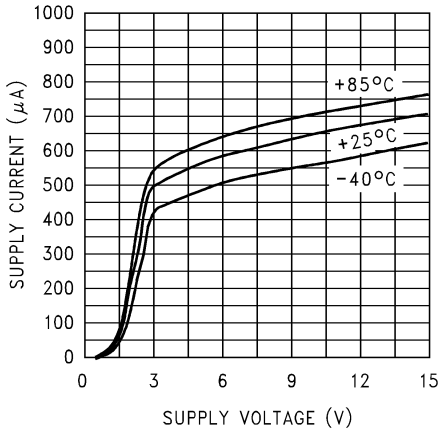


Figure 5-23. Supply Current vs Supply Voltage

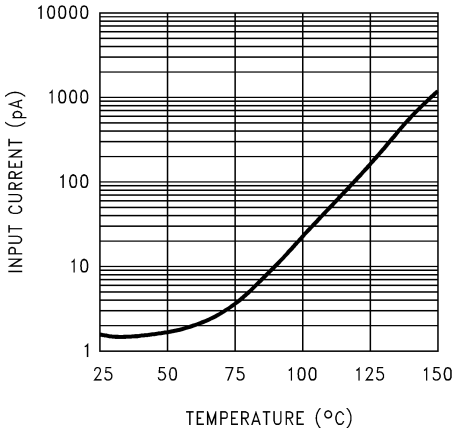


Figure 5-24. Input Current vs Temperature

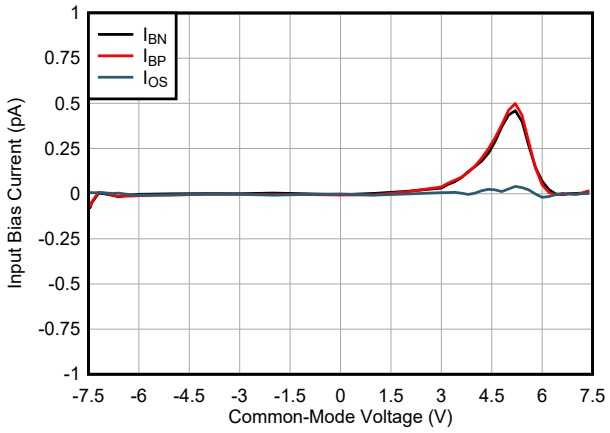


Figure 5-25. Input Bias Current vs Common-Mode Voltage

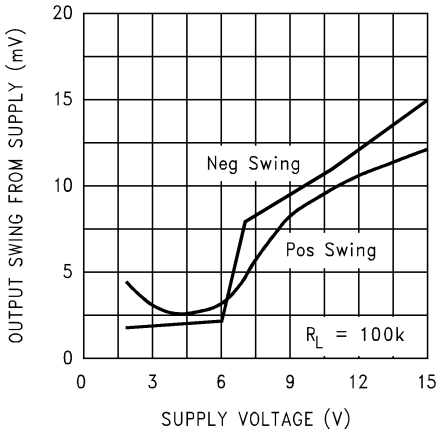


Figure 5-26. Output Voltage Swing vs Supply Voltage

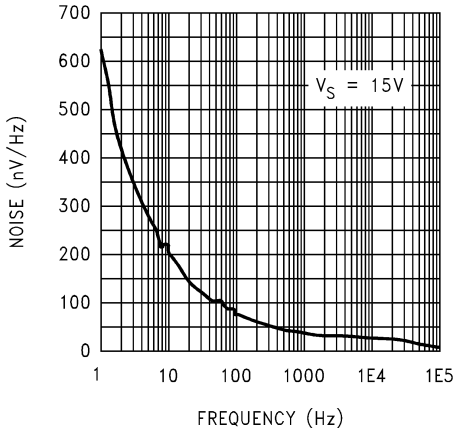


Figure 5-27. Input Voltage Noise vs Frequency

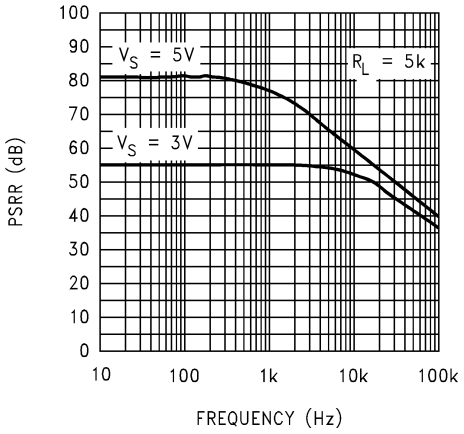


Figure 5-28. Positive PSRR vs Frequency

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

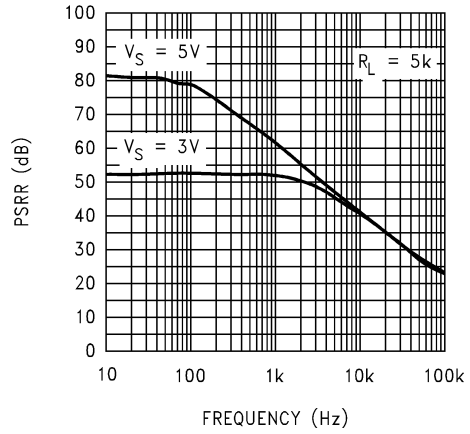


Figure 5-29. Negative PSRR vs Frequency

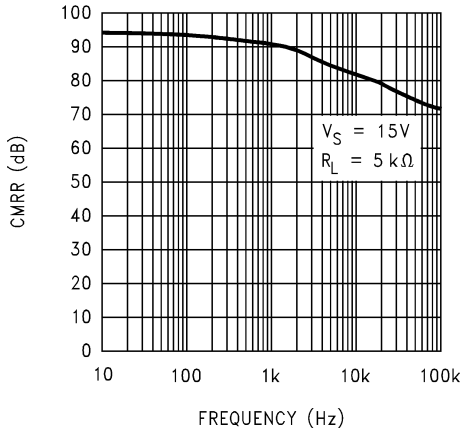


Figure 5-30. CMRR vs Frequency

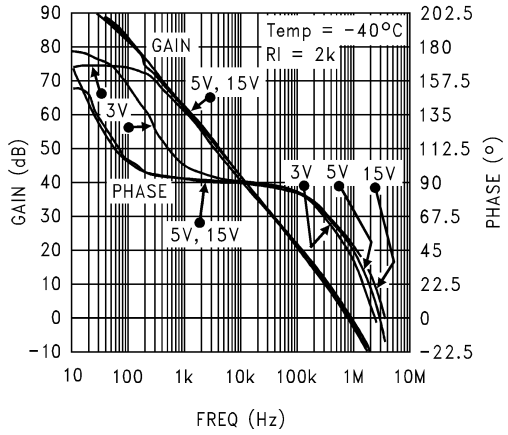


Figure 5-31. Open-Loop Frequency Response at –40°C

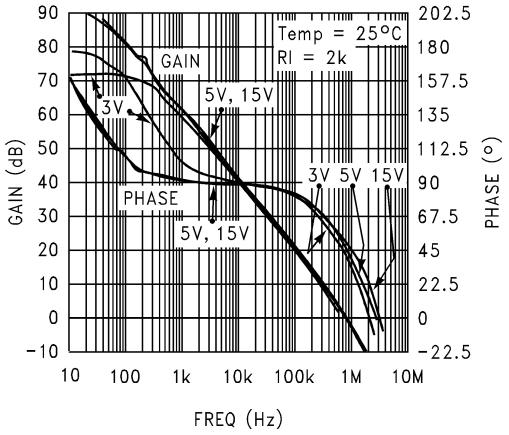


Figure 5-32. Open-Loop Frequency Response at 25°C

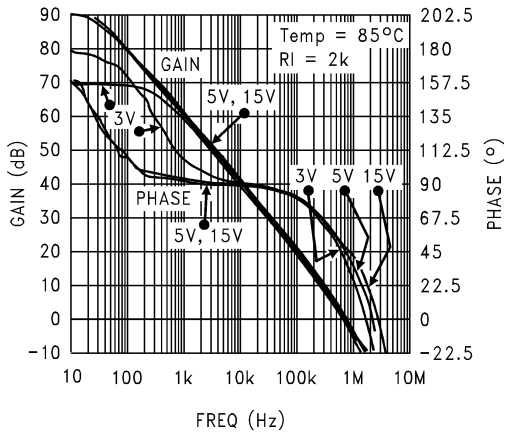


Figure 5-33. Open-Loop Frequency Response at 85°C

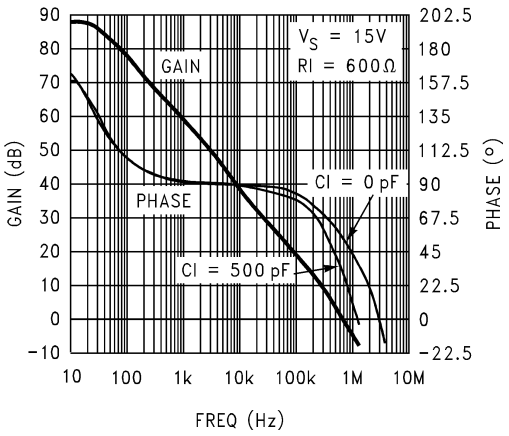


Figure 5-34. Gain and Phase vs Capacitive Load

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

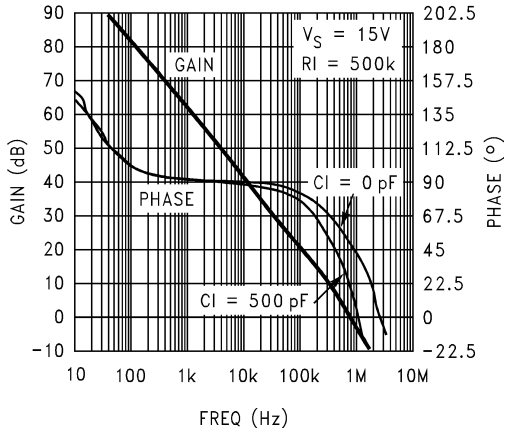


Figure 5-35. Gain and Phase vs Capacitive Load

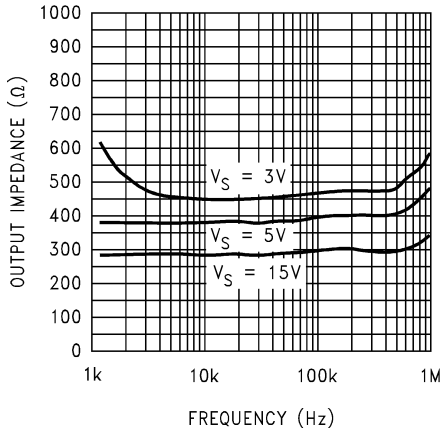


Figure 5-36. Output Impedance vs Frequency

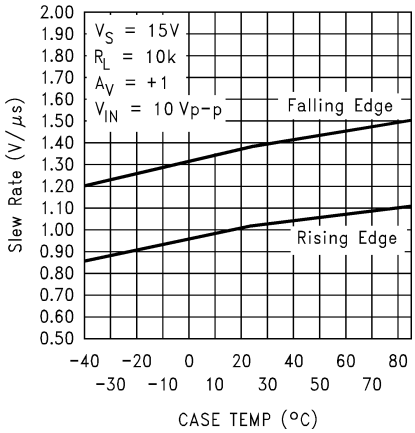


Figure 5-37. Slew Rate vs Temperature

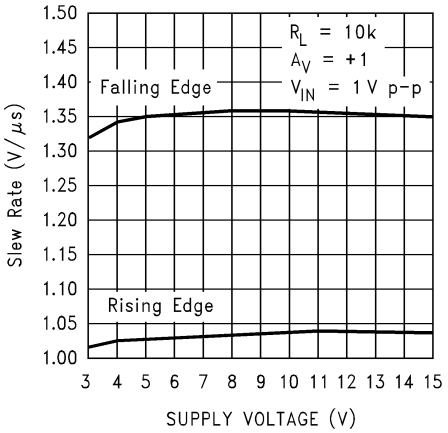


Figure 5-38. Slew Rate vs Supply Voltage

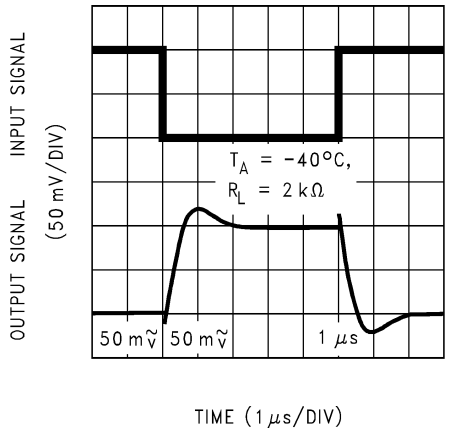


Figure 5-39. Inverting Small-Signal Pulse Response

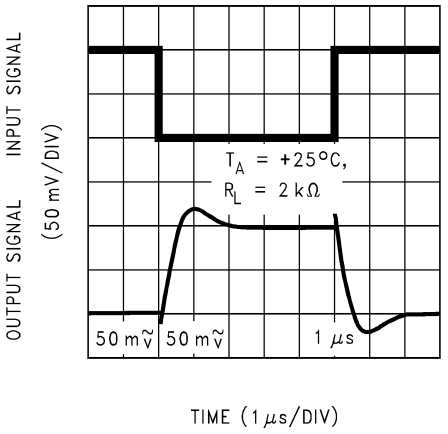


Figure 5-40. Inverting Small-Signal Pulse Response

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

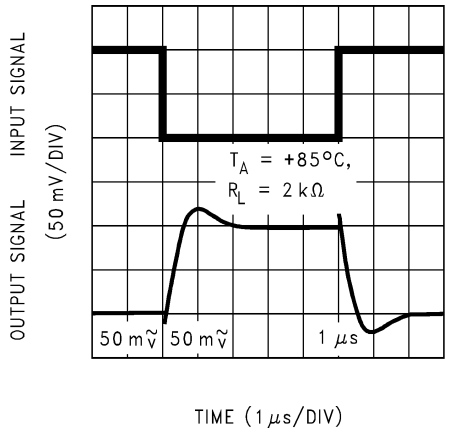


Figure 5-41. Inverting Small-Signal Pulse Response

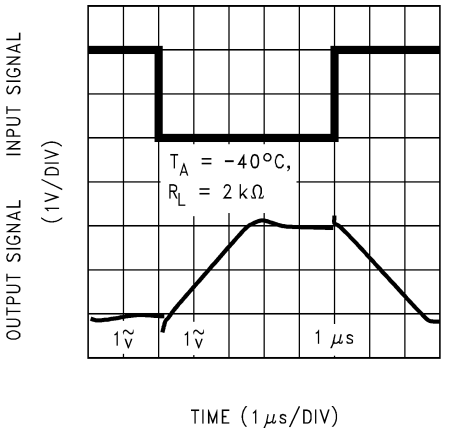


Figure 5-42. Inverting Large-Signal Pulse Response

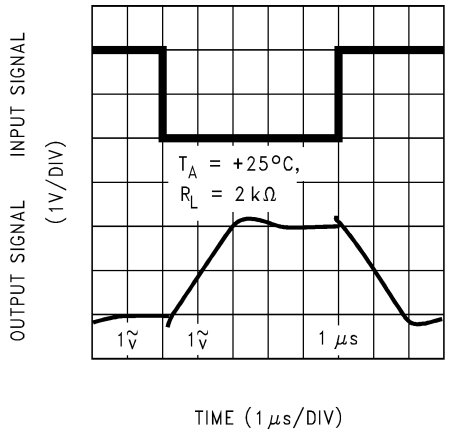


Figure 5-43. Inverting Large-Signal Pulse Response

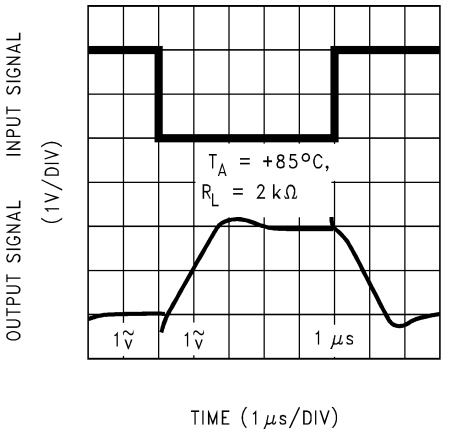


Figure 5-44. Inverting Large-Signal Pulse Response

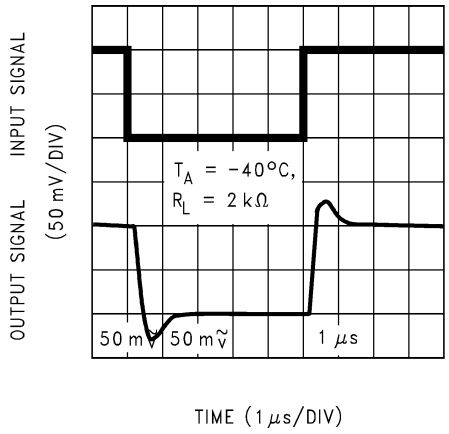


Figure 5-45. Noninverting Small-Signal Pulse Response

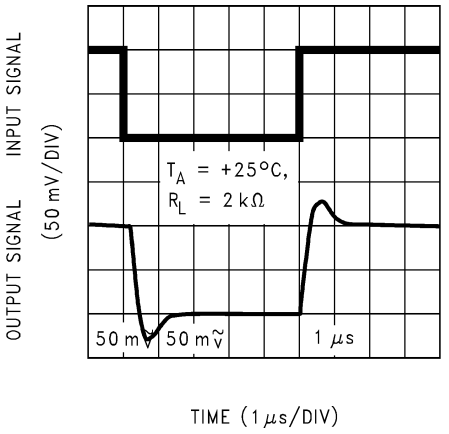


Figure 5-46. Noninverting Small-Signal Pulse Response

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

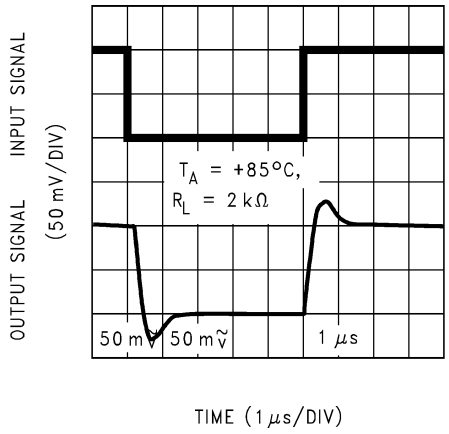


Figure 5-47. Noninverting Small-Signal Pulse Response

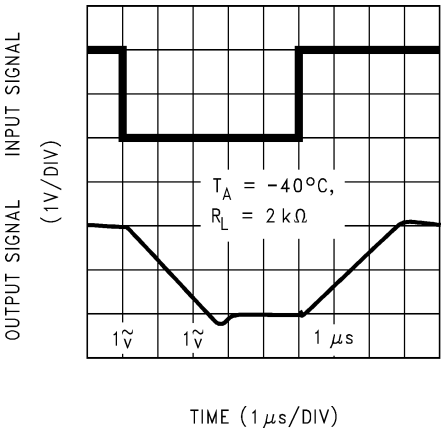


Figure 5-48. Noninverting Large-Signal Pulse Response

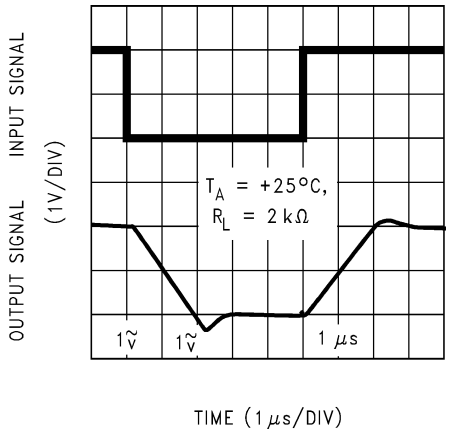


Figure 5-49. Noninverting Large-Signal Pulse Response

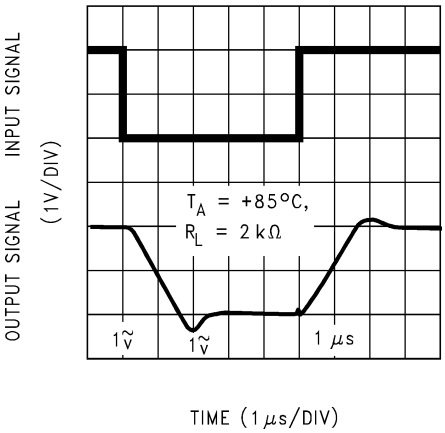


Figure 5-50. Noninverting Large-Signal Pulse Response

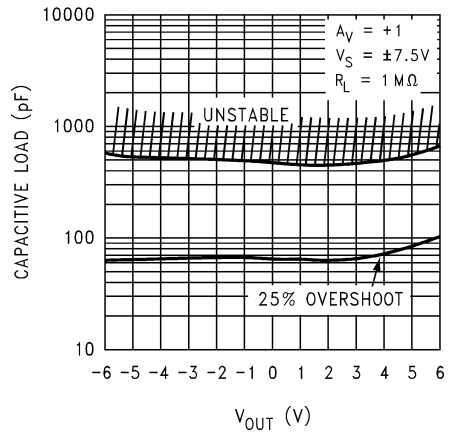


Figure 5-51. Stability vs Capacitive Load

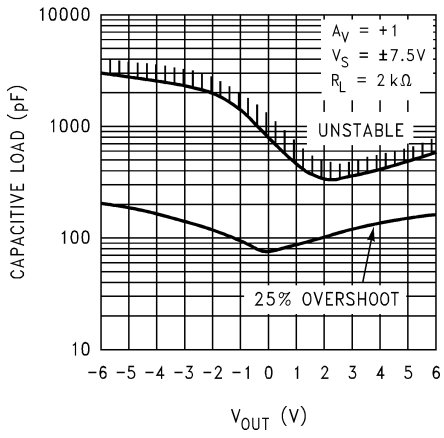


Figure 5-52. Stability vs Capacitive Load

5.12 Typical Characteristics for V_S = 15V (continued)

at V+ = 15V, V– = 0V, and T_A = 25°C (unless otherwise specified)

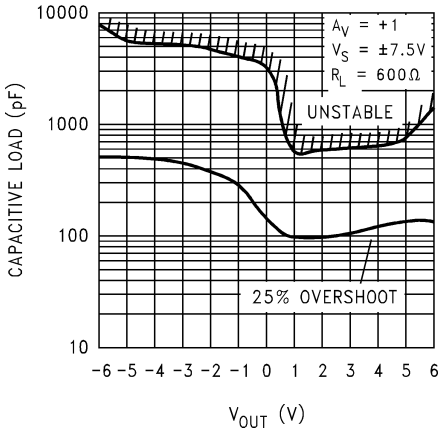


Figure 5-53. Stability vs Capacitive Load

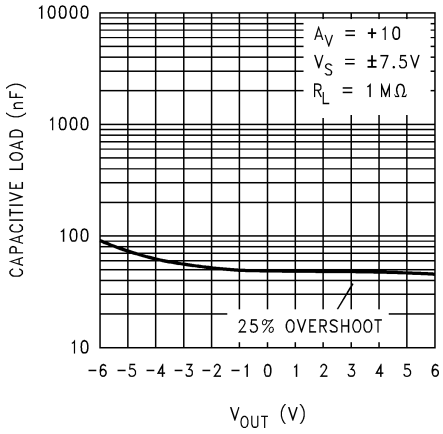


Figure 5-54. Stability vs Capacitive Load

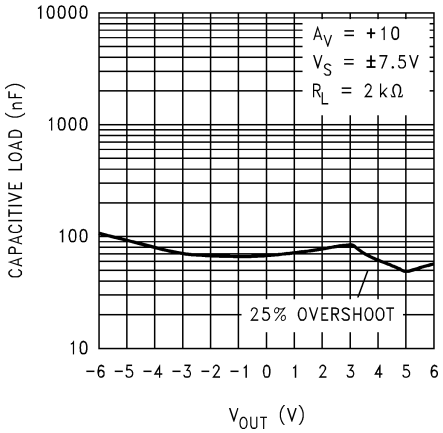


Figure 5-55. Stability vs Capacitive Load

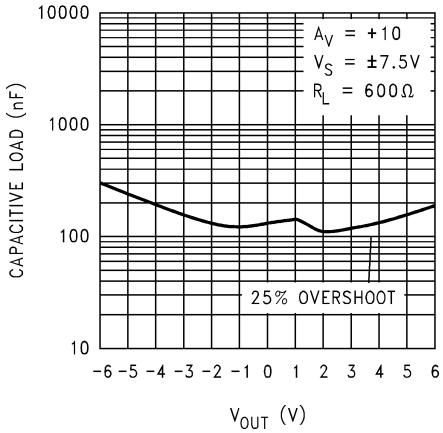


Figure 5-56. Stability vs Capacitive Load

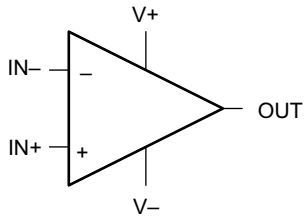
6 Detailed Description

6.1 Overview

The LMC7101Q-Q1 is a single-channel, low-power operational amplifier available in a space-saving SOT-23 package, offering rail-to-rail input and output operation across a wide range of power-supply configurations.

The LMC7101Q-Q1 is also available in a commercial-grade variant, see LMC7101.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Benefits of the LMC7101 Tiny Amplifier

6.3.1.1 Size

The small footprint of the SOT-23-5 packaged tiny amplifier, (0.12in × 0.118in, 3.05mm × 3mm) saves space on printed circuit boards, and enable the design of smaller electronic products. Many customers prefer smaller and lighter products because the designs can contribute to overall weight reduction in vehicles.

6.3.1.2 Height

The 0.056 inches (1.43mm) height of the tiny LMC7101Q-Q1 amplifier makes the device an excellent choice for use in a wide range of circuit boards in which a thin profile is required.

6.3.1.3 Signal Integrity

Signals can pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, the tiny amplifier can be placed closer to the signal source, thus reducing noise pickup and increasing signal integrity. The tiny amplifier can also be placed next to the signal destination, such as a buffer, for the reference of an analog-to-digital converter.

6.3.1.4 Simplified Board Layout

The tiny LMC7101Q-Q1 amplifier can simplify board layout in several ways. Avoid long PCB traces by correctly placing amplifiers instead of routing signals to a dual or quad device. By using multiple tiny amplifiers instead of duals or quads, complex signal routing and possibly crosstalk can be reduced.

6.3.1.5 Low THD

The high open-loop gain of the LMC7101Q-Q1 amplifier helps to achieve very low audio distortion—typically 0.01% at 10kHz with a 10kΩ load at 5V supplies. This makes the tiny amplifier an excellent choice for automotive audio and low-frequency signal-processing applications.

6.3.1.6 Low Supply Current

The typical 0.5mA supply current of the LMC7101Q-Q1 can help improve thermal performance on high density circuit boards, and can allow the reduction of the overall board size in some applications.

6.3.1.7 Wide Voltage Range

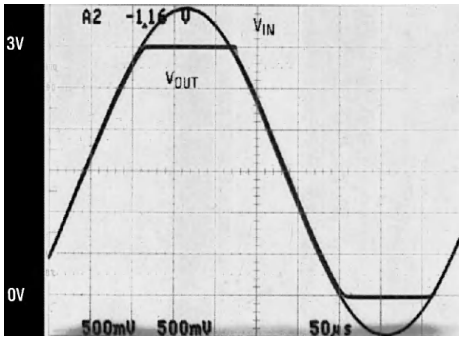
The LMC7101 is characterized at 15V, 5V and 3V. Performance data is provided at these popular voltages. This wide voltage range makes the LMC7101Q-Q1 a good choice for devices where the supply voltage can vary.

6.4 Device Functional Modes

6.4.1 Input Common-Mode Voltage Range

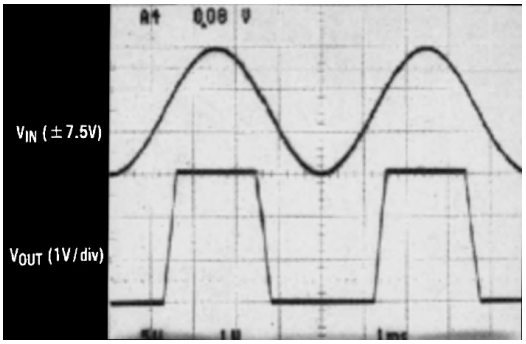
The LMC7101Q-Q1 does not exhibit phase inversion when an input voltage exceeds the negative supply voltage. Figure 6-1 shows an input voltage exceeding both supplies with no resulting phase inversion of the output.

The absolute maximum input voltage is 300mV beyond either rail at room temperature. Voltages greatly exceeding this maximum rating, as in Figure 6-2, can cause excessive current to flow in or out of the input pins, thus adversely affecting reliability.



The input voltage signal exceeds the amplifier power supply voltage with no output phase inversion.

Figure 6-1. Input Voltage



The ±7.5V input signal greatly exceeds the 3V supply in Figure 6-3 causing no phase inversion due to R_I.

Figure 6-2. Input Signal

Applications that exceed this rating must externally limit the maximum input current to ±5mA with an input resistor as shown in Figure 6-3.

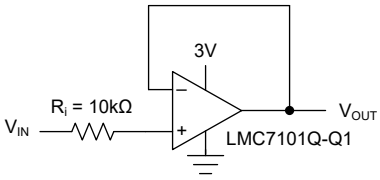


Figure 6-3. R_I Input Current Protection for Voltages Exceeding the Supply Voltage

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Rail-to-Rail Output

The approximate output resistance of the LMC7101Q-Q1 is 180Ω sourcing and 130Ω sinking at V_S = 3V and 110Ω sourcing and 80Ω sinking at V_S = 5V. Using the calculated output resistance, maximum output voltage swing can be estimated as a function of load.

7.1.2 Capacitive Load Tolerance

The LMC7101Q-Q1 can typically directly drive a 100pF load with V_S = 15V at unity gain without oscillating. The unity gain follower is the most sensitive configuration. Direct capacitive loading reduces the phase margin of operational amplifiers. The combination of the output impedance and the capacitive load of the operational amplifier induces phase lag, which results in either an underdamped pulse response or oscillation.

Capacitive load compensation can be accomplished using resistive isolation as shown in Figure 7-1. This simple technique is useful for isolating the capacitive input of multiplexers and A/D converters.

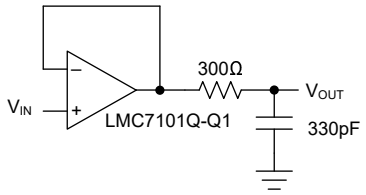


Figure 7-1. Resistive Isolation of a 330pF Capacitive Load

7.1.3 Compensating for Input Capacitance When Using Large Value Feedback Resistors

When using very large value feedback resistors, (usually >500 kΩ) the large feed back resistance can react with the input capacitance due to transducers, photo diodes, and circuit board parasitics to reduce phase margins.

The effect of input capacitance can be compensated for by adding a feedback capacitor. The feedback capacitor (as in Figure 7-2), C_f is first estimated by Equation 1 and Equation 2, which typically provides significant overcompensation.

$$\frac{1}{2\pi R_1 C_{IN}} \geq \frac{1}{2\pi R_2 C_f} \quad (1)$$

$$2\pi R_1 C_{IN} \leq 2\pi R_2 C_f \quad (2)$$

Printed circuit board stray capacitance can be larger or smaller than that of a breadboard, so the actual optimum value for C_F can be different. The values of C_F must be checked on the actual circuit.

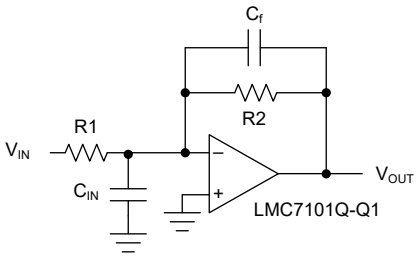


Figure 7-2. Canceling the Effect of Input Capacitance

7.2 Typical Application

Figure 7-3 shows a high input impedance noninverting circuit. This circuit gives a closed-loop gain equal to the ratio of the sum of R1 and R2 to R1 and a closed-loop 3dB bandwidth equal to the amplifier unity-gain frequency divided by the closed-loop gain. This design has the benefit of a very high input impedance, which is equal to the differential input impedance multiplied by loop gain (open loop gain / closed loop gain). In dc-coupled applications, input impedance is not as important as input current and the voltage drop across the source resistance. The amplifier output can go into saturation if the input is allowed to float, which can be important if the amplifier must be switched from source to source.

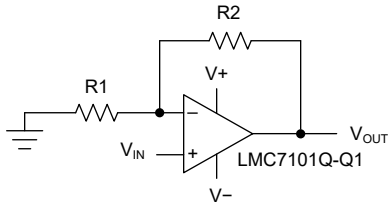


Figure 7-3. Example Application

7.2.1 Design Requirements

For this example application, the supply voltage is 5V, and 100 × ±5% of noninverting gain is necessary. The signal input impedance is approximately 10kΩ.

7.2.2 Detailed Design Procedure

Use the equation for a noninverting amplifier configuration; G = 1 + R2 / R1, set R1 to 10kΩ, and R2 to 99 × R1, which is 990kΩ. Replacing the 990kΩ resistor with a more readily available 1MΩ resistor results in a gain of 101, which is within the desired gain tolerance. The gain-frequency characteristic of the amplifier and the feedback network must be such that oscillation does not occur. To meet this condition, the phase shift through amplifier and feedback network must never exceed 180° for any frequency where the gain of the amplifier and the feedback network is greater than unity. In practical applications, the phase shift must not approach 180° because this is the situation of conditional stability. The most critical case occurs when the attenuation of the feedback network is zero.

7.2.3 Application Curve

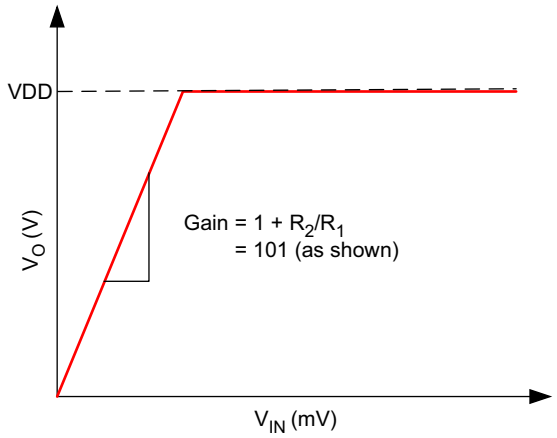


Figure 7-4. Output Response

7.3 Power Supply Recommendations

For proper operation, the power supplies must be decoupled. For supply decoupling, TI recommends placing 10nF to 1µF capacitors as close as possible to the operational-amplifier power supply pins. For single supply configurations, place a capacitor between the V+ and V− supply pins. For dual supply configurations, place one capacitor between V+ and ground, and place a second capacitor between V− and ground. Bypass capacitors must have a low ESR of less than 0.1Ω.

7.4 Layout

7.4.1 Layout Guidelines

Care must be taken to minimize the loop area formed by the bypass capacitor connection between supply pins and ground. A ground plane underneath the device is recommended; any bypass components to ground must have a nearby via to the ground plane. The optimum bypass capacitor placement is closest to the corresponding supply pin. Use of thicker traces from the bypass capacitors to the corresponding supply pins can lower the power-supply inductance and provide a more stable power supply.

The feedback components must be placed as close as possible to the device to minimize stray parasitics.

7.4.2 Layout Example

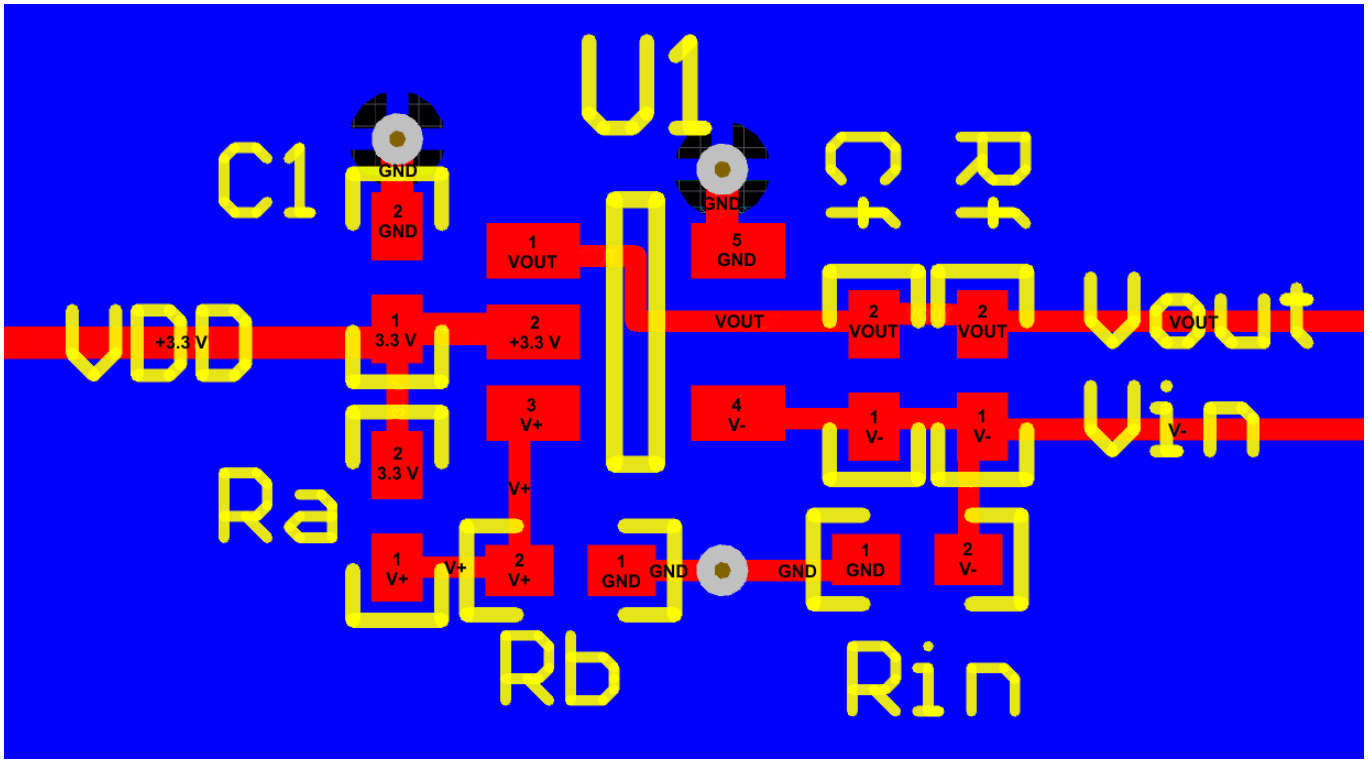


Figure 7-5. LMC7101Q-Q1 Example Layout

8 Device and Documentation Support

8.1 Documentation Support

8.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *LMC66x CMOS Dual Operational Amplifiers* data sheet
- Texas Instruments, *RES11A Matched, Thin-Film Resistor Dividers With 1kΩ Inputs* data sheet

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.4 Trademarks

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8.5 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary	This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision G (September 2015) to Revision H (January 2025)	Page
• Moved LMC7101 commercial device into new SBOSAL2 data sheet	1
• Updated *Features*	1
• Updated *Description*	1
• Updated pin diagram figure and pin names in *Pin Configuration and Functions*	2
• Deleted Machine model (MM) from *ESD Ratings*	3
• Changed temperature test conditions from junction temperature, T_J to ambient temperature, T_A throughout	3
• Updated *Thermal Information*	3
• Updated formatting across all *Electrical Characteristics*	4
• Updated parameter names to be consistent with modern data sheets	4
• Added missing input offset voltage drift temperature condition in all *Electrical Characteritics*	4
• Updated temperature range conditions in input bias current and input offset current in all Electrical Characteristics	4
• Changed input common-mode voltage condition from CMRR ≥ 50dB to CMRR ≥ 47dB	4
• Changed CMRR MIN from 50dB to 47dB	4
• Deleted footnotes 1 and 2 in all *Electrical Characteristics*	4

- Changed input common-mode voltage condition from CMRR > 50dB to CMRR > 47dB
- Changed CMRR MIN from 60dB to 47dB and TYP from 74dB to 70dB
- Changed CMRR MIN from 60dB to 52dB and TYP from 82dB to 75dB
- Changed CMRR MIN for T_A = –40°C to +125°C from 60dB to 51dB and TYP from 82dB to 74dB
- Changed input common-mode voltage test condition from (V+) = 5V to (V+) = 15V
- Changed CMRR MIN from 65dB to 62dB
- Deleted Figures 6, 11, 14, 17, 20, 23, and 37
- Added Figure 5-6
- Added Figures 5-21 and 5-25
- Updated description text in *Size*
- Updated Figure 7-3, *Example Application* to show correct noninverting circuit

Changes from Revision F (March 2013) to Revision G (September 2015) **Page**

- Added *Pin Configuration and Functions*, *ESD Ratings*, *Feature Description*, *Device Functional Modes*, *Application and Implementation*, *Power Supply Recommendations*, *Layout*, *Device and Documentation Support*, and *Mechanical, Packaging, and Orderable Information* sections

Changes from Revision E (March 2013) to Revision F (March 2013) **Page**

- Changed layout of National Semiconductor Data Sheet to TI format

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LMC7101QM5/NOPB	OBSOLETE	SOT-23	DBV	5		TBD	Call TI	Call TI	-40 to 125	AT6A	
LMC7101QM5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	Call TI | SN	Level-1-260C-UNLIM	-40 to 125	AT6A	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

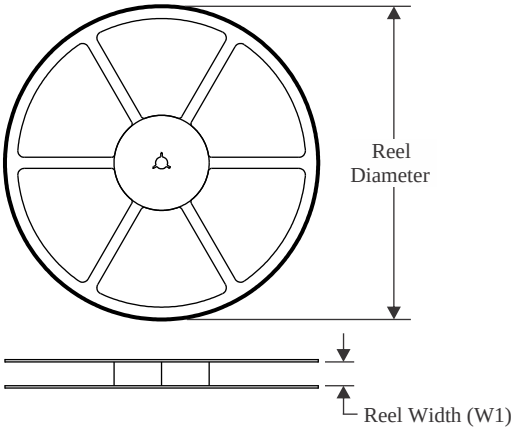
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

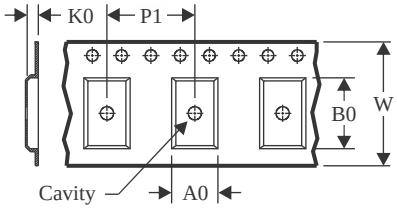
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

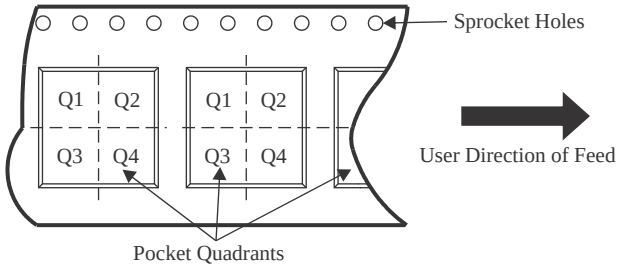


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

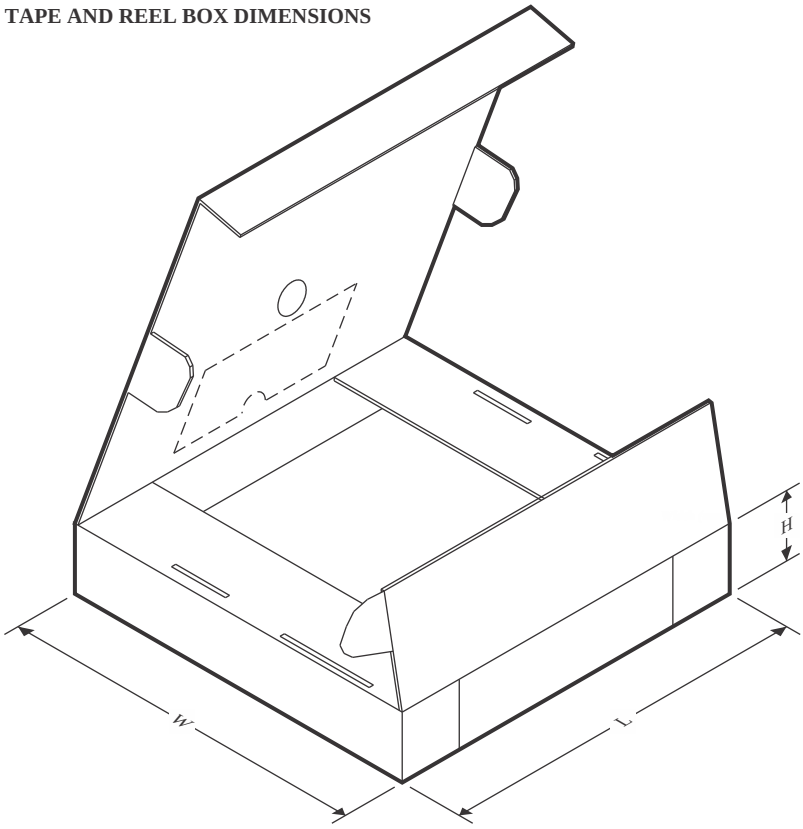
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

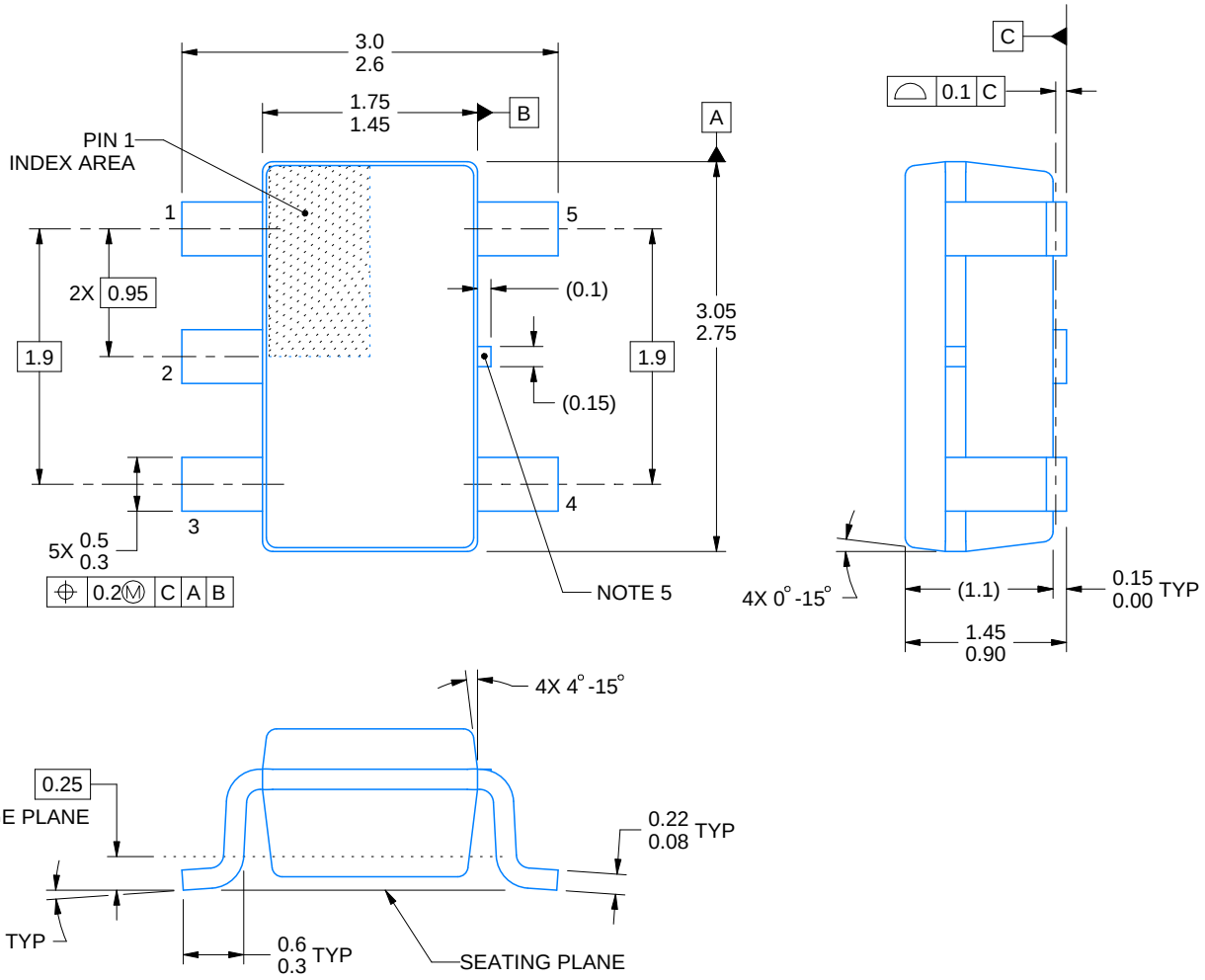
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMC7101QM5X/NOPB	SOT-23	DBV	5	3000	208.0	191.0	35.0

PACKAGE OUTLINE

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



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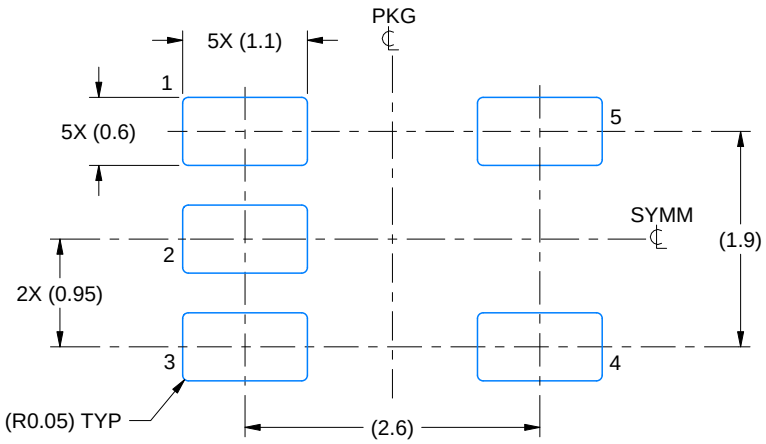
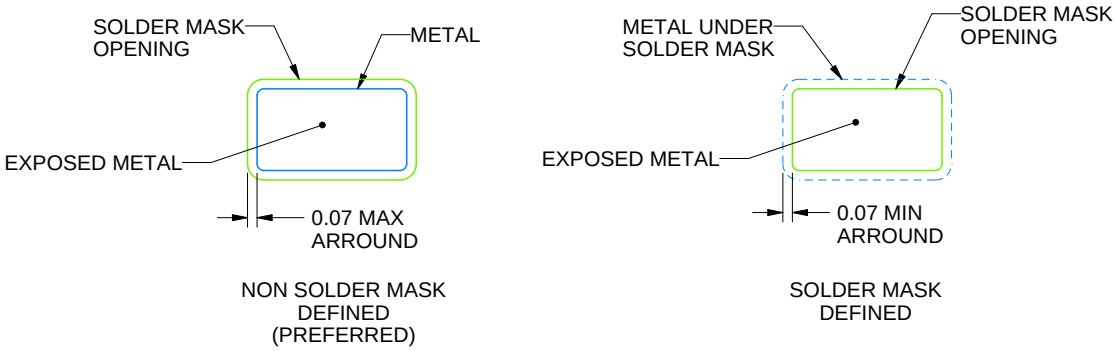
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Refernce JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

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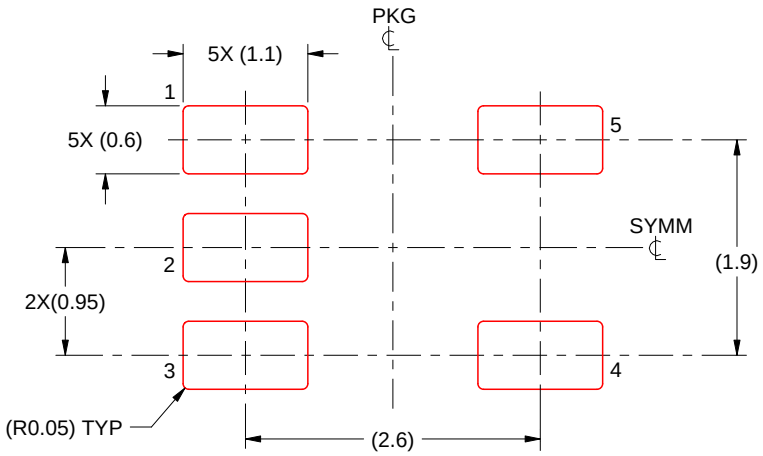
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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